



Introduction

This application note is intended for system designers who require a hardware implementation overview of the development board features such as the power supply, the clock management, the reset control, the boot mode settings and the debug management. It shows how to use STM32L1xxx product families and describes the minimum hardware resources required to develop an STM32L1xxx application.

Detailed reference design schematics are also contained in this document with descriptions of the main components, interfaces and modes.

Table 1. Applicable products

Type	Product sub-class
Microcontroller	STM32L1xxx

Contents

- 1 Power supplies 6**
 - 1.1 Introduction 6
 - 1.1.1 Independent A/D converter supply and reference voltage 7
 - 1.1.2 Independent LCD supply 8
 - 1.1.3 Voltage regulator 8
 - 1.2 Power supply schemes 9
 - 1.3 Reset and power supply supervisor 9
 - 1.3.1 Power-on reset (POR)/power-down reset (PDR), brownout reset (BOR) 11
 - 1.3.2 Programmable voltage detector (PVD) 11
 - 1.3.3 Brownout reset (BOR) 12
 - 1.3.4 System reset 13

- 2 Clocks 14**
 - 2.1 MSI clock 14
 - 2.2 HSE OSC clock 15
 - 2.2.1 External source (HSE bypass) 15
 - 2.2.2 External crystal/ceramic resonator (HSE crystal) 15
 - 2.3 LSE OSC clock 16
 - 2.3.1 External source (LSE bypass) 16
 - 2.3.2 External crystal/ceramic resonator (LSE crystal) 16
 - 2.4 Clock security system (CSS) 17

- 3 Boot configuration 18**
 - 3.1 Boot mode selection 18
 - 3.2 Boot pin connection 18
 - 3.3 Embedded boot loader mode 19

- 4 Debug management 20**
 - 4.1 Introduction 20
 - 4.2 SWJ debug port (serial wire and JTAG) 20
 - 4.3 Pinout and debug port pins 20
 - 4.3.1 SWJ debug port pins 21

4.3.2	Flexible SWJ-DP pin assignment	21
4.3.3	Internal pull-up and pull-down resistors on JTAG pins	22
4.3.4	SWJ debug port connection with standard JTAG connector	22
5	Recommendations	23
5.1	Printed circuit board	23
5.2	Component position	23
5.3	Ground and power supply (V_{SS} , V_{DD})	23
5.4	Decoupling	23
5.5	Other signals	24
5.6	Unused I/Os and features	24
6	Reference design	25
6.1	Description	25
6.1.1	Clock	25
6.1.2	Reset	25
6.1.3	Boot mode	25
6.1.4	SWJ interface	25
6.1.5	Power supply	25
6.2	Component references	26
7	Revision history	30

List of tables

Table 1.	Applicable products	1
Table 2.	Boot modes	18
Table 3.	Debug port pin assignment	21
Table 4.	SWJ I/O pin availability	21
Table 5.	Mandatory components	26
Table 6.	Optional components	26
Table 7.	Reference connection for all packages	28
Table 8.	Document revision history	30

List of figures

Figure 1.	Power supply overview	6
Figure 2.	Power supply scheme	9
Figure 3.	Power supply supervisors	10
Figure 4.	Power on reset/power down reset waveform	11
Figure 5.	PVD thresholds	12
Figure 6.	Reset circuit	13
Figure 7.	External clock	15
Figure 8.	Crystal/ceramic resonators	15
Figure 9.	External clock	16
Figure 10.	Crystal/ceramic resonators ⁽²⁾	16
Figure 11.	Boot mode selection implementation example	18
Figure 12.	Host-to-board connection	20
Figure 13.	JTAG connector implementation	22
Figure 14.	Typical layout for V_{DD}/V_{SS} pair	24
Figure 15.	STM32L152VB(T6) microcontroller reference schematic	27

1 Power supplies

1.1 Introduction

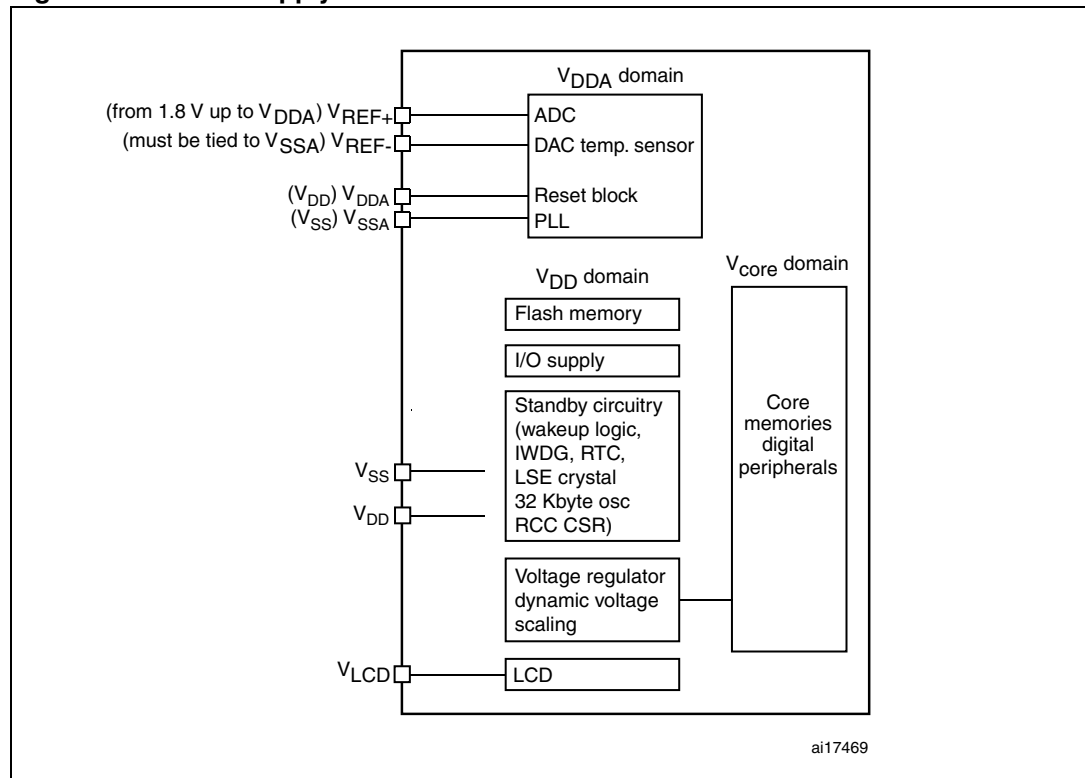
The device requires a 2.0 V to 3.6 V operating voltage supply (V_{DD}), to be fully functional at full speed. This maximum frequency is only achieved when the digital power voltage V_{CORE} is equal to 1.8 V (product voltage range 1).

Product voltage range 2 ($V_{CORE} = 1.5$ V) and 3 ($V_{CORE} = 1.2$ V) can be selected when the V_{DD} operates from 1.65 V to 3.6 V. Frequency is limited to 16 MHz and 4 MHz when the device is in product voltage range 2 and 3 respectively.

When the ADC and brownout reset (BOR) are not used, the device can operate at power voltages below 1.8 V down to 1.65 V.

Digital power voltage (V_{CORE}) is provided with an embedded linear voltage regulator with three different programmable ranges from 1.2 to 1.8 V (typical).

Figure 1. Power supply overview



Note: V_{DDA} and V_{SSA} must be connected to V_{DD} and V_{SS} , respectively.

1.1.1 Independent A/D converter supply and reference voltage

To improve conversion accuracy, the ADC and the DAC have an independent power supply that can be filtered separately, and shielded from noise on the PCB.

- The ADC voltage supply input is available on a separate V_{DDA} pin
- An isolated supply ground connection is provided on the V_{SSA} pin

V_{DDA} and V_{REF} require a stable voltage. The consumption on V_{DDA} can reach several mA (see $I_{DD}(ADCx)$, $I_{DD}(DAC)$, $I_{DD}(COMPx)$, I_{VDDA} , and I_{VREF} in the product datasheets for further information).

When available (depending on the package), V_{REF-} must be tied to V_{SSA} .

On BGA 64-pin and all 100-pin or more packages

To ensure a better accuracy on low-voltage inputs and outputs, the user can connect to V_{REF+} , a separate external reference voltage which is lower than V_{DD} . V_{REF+} is the highest voltage, represented by the full scale value, for an analog input (ADC) or output (DAC) signal.

- For ADC
 - $2.4\text{ V} \leq V_{REF+} = V_{DDA}$ for full speed (ADCCLK = 16 MHz, 1 Msps)
 - $1.8\text{ V} \leq V_{REF+} = V_{DDA}$ for medium speed (ADCCLK = 8 MHz, 500 Ksps)
 - $2.4\text{ V} \leq V_{REF+} \neq V_{DDA}$ for medium speed (ADCCLK = 8 MHz, 500 Ksps)
 - $1.8\text{ V} \leq V_{REF+} < V_{DDA}$ for low speed (ADCCLK = 4 MHz, 250 Ksps)
 - When product voltage range 3 is selected ($V_{CORE} = 1.2\text{ V}$), the ADC is low speed (ADCCLK = 4 MHz, 250 Ksps)
- For DAC
 - $1.8\text{ V} \leq V_{REF+} < V_{DDA}$

On packages with 64 pins or less (except BGA package)

V_{REF+} and V_{REF-} pins are not available. They are internally connected to the ADC voltage supply (V_{DDA}) and ground (V_{SSA}).

1.1.2 Independent LCD supply

The V_{LCD} pin is provided to control the contrast of the glass LCD. This pin can be used in two ways:

- It can receive, from an external circuitry, the desired maximum voltage that is provided on the segment and common lines to the glass LCD by the microcontroller.
- It can also be used to connect an external capacitor that is used by the microcontroller for its voltage step-up converter. This step-up converter is controlled by software to provide the desired voltage to the segment and common lines of the glass LCD.

The voltage provided to the segment and common lines defines the contrast of the glass LCD pixels. This contrast can be reduced when the dead time between frames is configured.

- When an external power supply is provided to the V_{LCD} pin, it should range from 2.5 V to 3.6 V. It does not depend on V_{DD} .
- When the LCD is based on the internal step-up converter, the V_{LCD} pin should be connected to a capacitor (see the product datasheets for further information).

1.1.3 Voltage regulator

The internal voltage regulator is always enabled after reset. It can be configured to provide the core with three different voltage ranges. Choosing a range with low V_{core} reduces the consumption but lowers the maximum acceptable core speed. Consumption ranges in decreasing consumption order are as follows:

- Range 1, available only for V_{DD} above 2.0 V, allows maximum speed
- Range 2 allows CPU frequency up to 16 MHz
- Range 3 allows CPU frequency up to 4 MHz

Voltage regulator works in three different modes depending on the application modes.

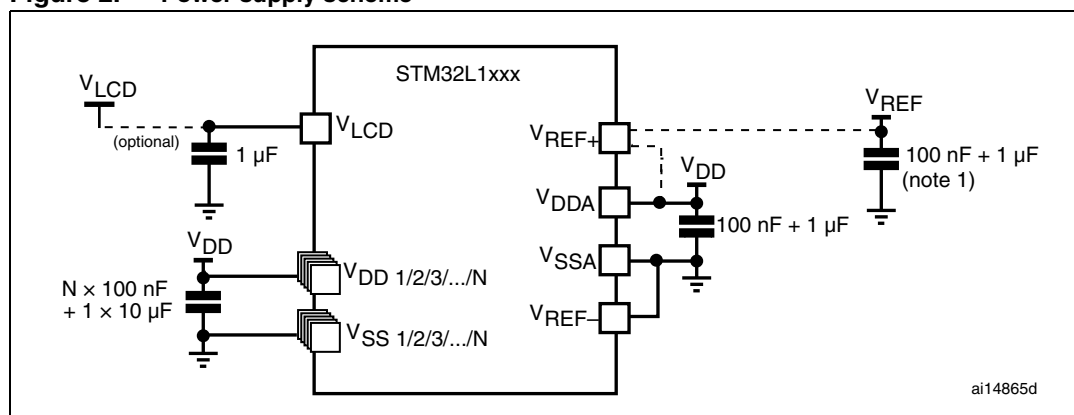
- In Run mode, the regulator supplies full power to the V_{core} domain (core, memories and digital peripherals).
- In Stop mode, Low power run and Low power wait modes, the regulator supplies low power to the V_{core} domain, preserving the contents of the registers and SRAM.
- In Standby mode, the regulator is powered off. The contents of the registers and SRAM are lost except for those concerned with the Standby circuitry.

1.2 Power supply schemes

The circuit is powered by a stabilized power supply, V_{DD} .

- The V_{DD} pins must be connected to V_{DD} with external decoupling capacitors; one single Tantalum or Ceramic capacitor (minimum 4.7 μF typical 10 μF) for the package + one 100 nF Ceramic capacitor for each V_{DD} pin).
- The V_{DDA} pin must be connected to two external decoupling capacitors (100 nF Ceramic capacitor + 1 μF Tantalum or Ceramic capacitor).
- The V_{REF+} pin can be connected to the V_{DDA} external power supply. If a separate, external reference voltage is applied on V_{REF+} , a 100 nF and a 1 μF capacitor must be connected on this pin. To compensate peak consumption on Vref, the 1 μF capacitor may be increased up to 10 μF when the sampling speed is low. When ADC or DAC is used, V_{REF+} must remain between 1.8 V and V_{DDA} . V_{REF+} can be grounded when ADC and DAC are not active; this enables the user to power down an external voltage reference.
- Additional precautions can be taken to filter analog noise: V_{DDA} can be connected to V_{DD} through a ferrite bead.

Figure 2. Power supply scheme



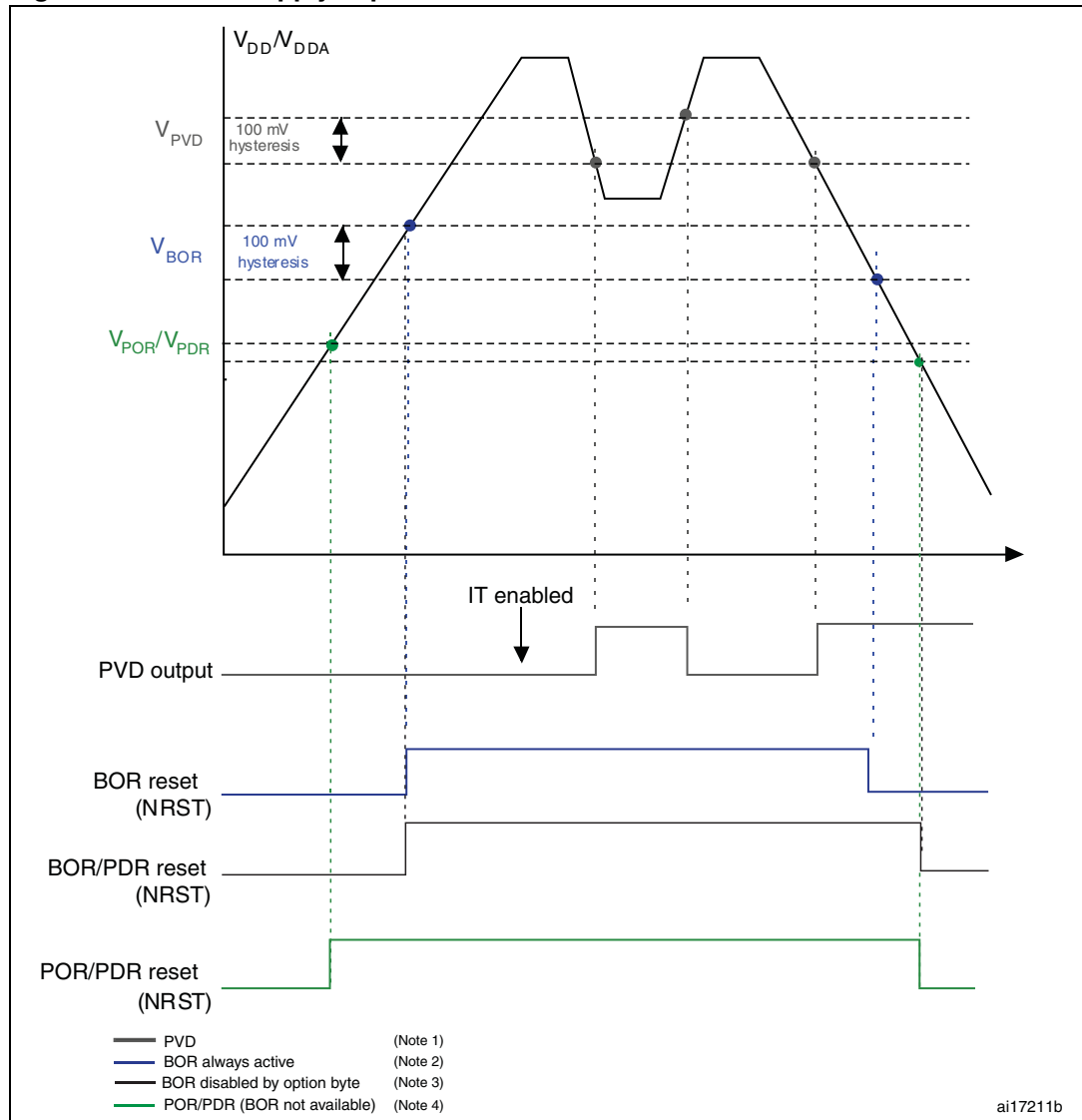
1. Optional. If a separate, external reference voltage is connected on V_{REF+} , the two capacitors (100 nF and 1 μF) must be connected.
2. V_{REF+} is either connected to V_{DDA} or to V_{REF-} .
3. N is the number of V_{DD} and V_{SS} inputs.

1.3 Reset and power supply supervisor

The input supply to the main and low power regulators is monitored by a power-on/power-down/brownout reset circuit. Power-on/power-down reset are a null power monitoring with fixed threshold voltages, whereas brownout reset gives the choice between several thresholds with a very low, but not null, power consumption.

In addition, the STM32L1xxx embeds a programmable voltage detector that compares the power supply with the programmable threshold. An interrupt can be generated when the power supply drops below the V_{PVD} threshold and/or when the power supply is higher than the V_{PVD} threshold. The interrupt service routine then generates a warning message and/or puts the MCU into a safe state.

Figure 3. Power supply supervisors



1. The PVD is available on all STM32L devices and it is enabled or disabled by software.
2. The BOR is available only on devices operating from 1.8 to 3.6 V, and unless disabled by option byte it masks the POR/PDR threshold.
3. When the BOR is disabled by option byte, the reset is asserted when V_{DD} goes below PDR level.
4. For devices operating from 1.65 to 3.6 V, there is no BOR and the reset is released when V_{DD} goes above POR level and asserted when V_{DD} goes below PDR level.

1.3.1 Power-on reset (POR)/power-down reset (PDR), brownout reset (BOR)

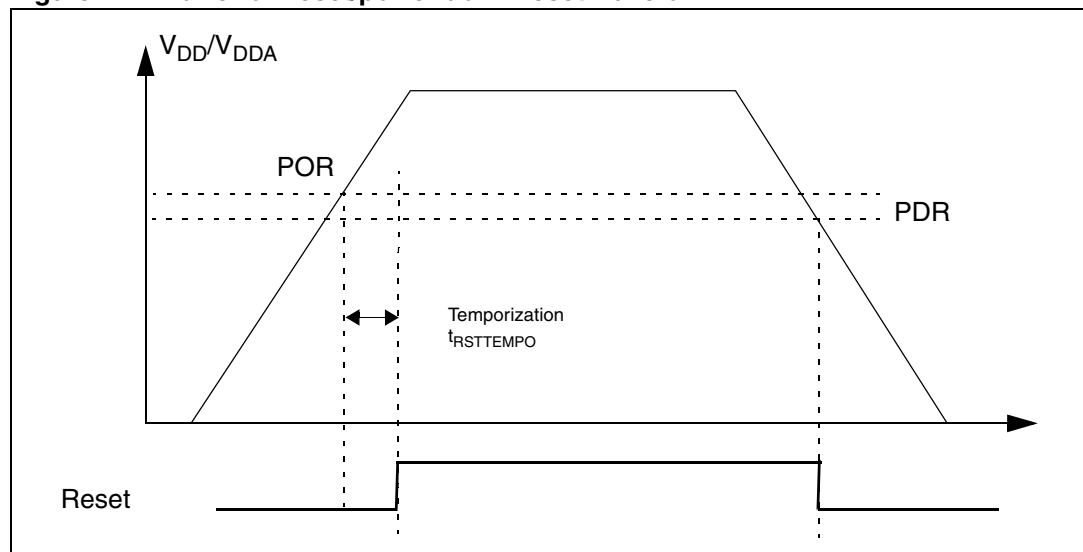
The monitoring voltage begins at 0.7 V.

During power-on, for devices operating between 1.8 and 3.6 V, the BOR keeps the device under reset until the supply voltages (V_{DD} and V_{DDIO}) come close to the lowest acceptable voltage (1.8 V). At power-up this internal reset is maintained during ~1 ms to wait for the supply to reach its final value and stabilize.

At power-down the reset is activated as soon as the power drops below the lowest limit (1.65 V).

At power-on, a defined reset should be maintained below 0.7 V. The upper threshold for a reset release is defined in the electrical characteristics section of the product datasheets.

Figure 4. Power on reset/power down reset waveform

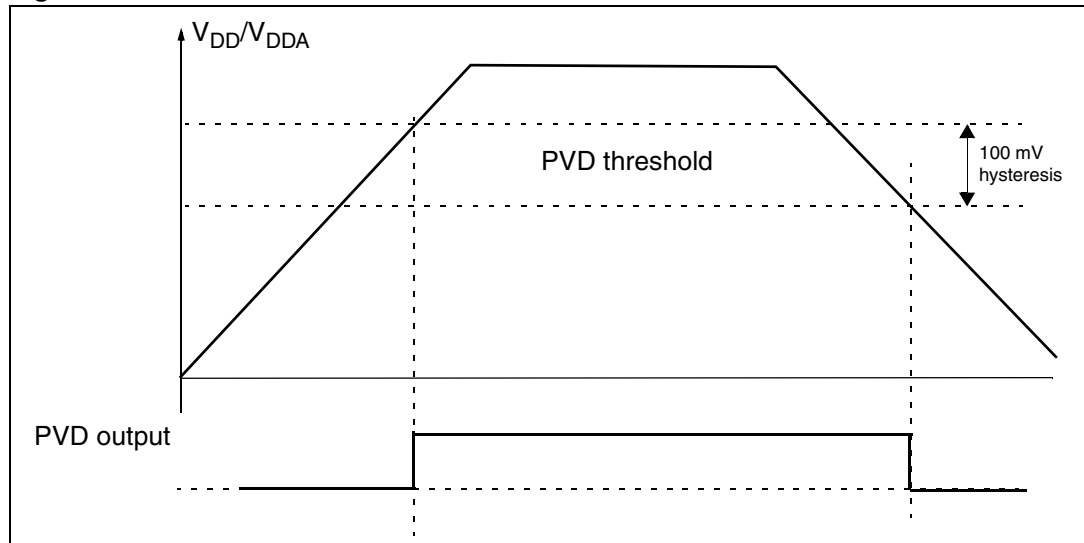


If you want to run the cpu at full speed the threshold should be raised to 2.0 V. For a programmable threshold above the chip lowest limit, a brownout reset can be configured to the desired value. The BOR can also be used to detect a power voltage drop earlier. The threshold values of the BOR can be configured through the FLASH_OBR option byte.

1.3.2 Programmable voltage detector (PVD)

The device features an embedded programmable voltage detector (PVD) that monitors the V_{DD}/V_{DDA} power supply and compares it to the V_{PVD} threshold. Seven different PVD levels can be selected by software between 1.85 V and 3.05 V, with a 200 mV step. An interrupt can be generated when V_{DD}/V_{DDA} drops below the V_{PVD} threshold and/or when V_{DD}/V_{DDA} is higher than the V_{PVD} threshold. The interrupt service routine then generates a warning message and/or puts the MCU into a safe state. The PVD is enabled by software configuration. As an example, the service routine can perform emergency shutdown tasks.

Figure 5. PVD thresholds



1.3.3 Brownout reset (BOR)

During power on, the brownout reset (BOR) keeps the device under reset until the supply voltage reaches the specified V_{BOR} threshold.

For devices operating from 1.65 to 3.6 V, the BOR option is not available and the power supply is monitored by the POR/PDR. As the POR/PDR thresholds are at 1.5 V, a “grey zone” exists between the V_{POR}/V_{PDR} thresholds and the minimum product operating voltage 1.65 V.

For devices operating from 1.8 to 3.6 V, the BOR is always active at power on and its threshold is 1.8 V.

When the system reset is released, the BOR level can be reconfigured or disabled by option byte loading.

If the BOR level is kept at the lowest level, 1.8 V at power-on and 1.65 V at power down, the system reset is fully managed by the BOR and the product operating voltages are within safe ranges.

When the BOR option is disabled by option byte, the power down reset is controlled by the PDR and a “grey zone” exists between the 1.65 V and V_{PDR} .

V_{BOR} is configured through device option bytes. By default, level 4 threshold is activated. Five programmable V_{BOR} thresholds can be selected (see product datasheets for actual V_{BOR0} to V_{BOR4} thresholds).

When the supply voltage (V_{DD}) drops below the selected V_{BOR} threshold, a device reset is generated. When the V_{DD} is above the V_{BOR} upper limit the device reset is released and the system can start.

BOR can be disabled by programming the device option bytes. To disable the BOR function, V_{DD} must have been higher than V_{BOR0} to start the device option byte programming sequence. The power-on and power-down is then monitored by the POR and PDR (see power-on reset (POR)/power-down reset (PDR) section in the product datasheets).

The BOR threshold hysteresis is ~100 mV (between the rising and the falling edge of the supply voltage).

1.3.4 System reset

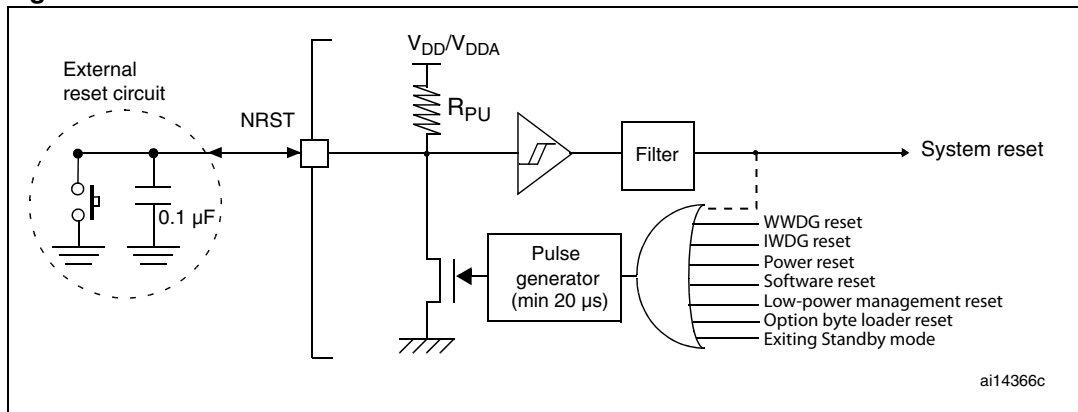
A system reset sets all registers to their reset values except for the RTC, backup registers and RCC control/status register, RCC_CSR.

A system reset is generated when one of the following events occurs:

1. A low level on the NRST pin (external reset)
2. Window watchdog end-of-count condition (WWDG reset)
3. Independent watchdog end-of-count condition (IWDG reset)
4. A reset bit set by software (SWreset)
5. Entering Standby or Stop mode configured to generate a reset (Low-power management reset)
6. Option byte loader reset
7. Exiting Standby mode

The reset source can be identified by checking the reset flags in the Control/Status register, RCC_CSR.

Figure 6. Reset circuit



The STM32L does not require an external reset circuit to power-up correctly. Only a pull-down capacitor is recommended to improve EMS performance by protecting the device against parasitic resets (see [Figure 6](#)).

Charging/discharging the pull-down capacitor thru the internal resistor adds to the device power consumption. The recommended value of 100 nF for the capacitor can be reduced to 10 nF to limit this power consumption.

2 Clocks

Four different clock sources can be used to drive the system clock (SYSCLK). They are:

- HSI ((high-speed internal) oscillator clock
- HSE (high-speed external) oscillator clock
- PLL clock
- MSI (multispeed internal) oscillator clock

The MSI is used as a system clock source after startup from reset, wake-up from Stop or Standby low power modes.

The devices have the following two secondary clock sources:

- 37 kHz low speed internal RC (LSI RC) which drives the independent watchdog and optionally the RTC used for auto-wakeup from Stop/Standby mode.
- 32.768 kHz low speed external crystal (LSE crystal) which optionally drives the real-time clock (RTCCLK)

Each clock source can be switched on or off independently when it is not used, to optimize power consumption.

Refer to the STM32L15xxx reference manual (RM0038) for a description of the clock tree.

2.1 MSI clock

The MSI clock signal is generated from an internal RC oscillator. Its frequency range can be adjusted by software through the RCC_ICSCR register. Seven frequency ranges are available: 65.5 kHz, 131 kHz, 262 kHz, 524 kHz, 1.05 MHz, 2.1 MHz (default value) and 4.2 MHz. Those frequencies are multiple values of 32.768 kHz.

The MSI clock is used as a system clock after a restart from reset.

The MSI RC oscillator has the advantage of providing a low-cost (no external components) low-power clock source. It is used as a wakeup clock in low power modes to reduce power consumption and wakeup time.

The MSIRDY flag in the RCC_CR register indicates whether the MSI RC is stable or not. At startup, the MSI RC output clock is not released until this bit is set by hardware.

The MSI RC can be switched on and off through the RCC_CR register (default is on).

If the application is subject to voltage or temperature variations, this may affect the RC oscillator speed. You can trim the MSI frequency in the application through the RCC_ICSCR register. Typically, this uses the HSE as reference (see RM0038 for details on clock measurement with TIM9/TIM10/TIM11). For more information refer to AN3300 *“How to calibrate an STM32L1xx internal RC oscillator”*.

2.2 HSE OSC clock

The high-speed external clock signal (HSE) can be generated from two possible clock sources:

- HSE user external clock (see [Figure 7](#))
- HSE external crystal/ceramic resonator (see [Figure 8](#))

Figure 7. External clock

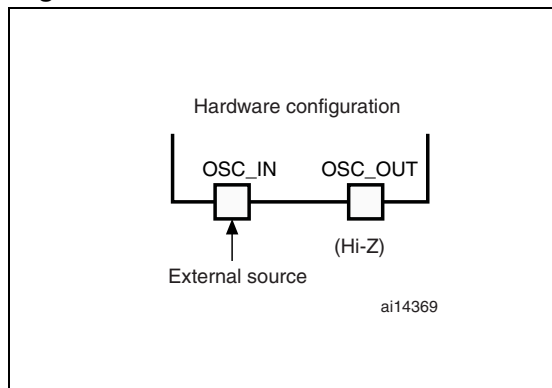
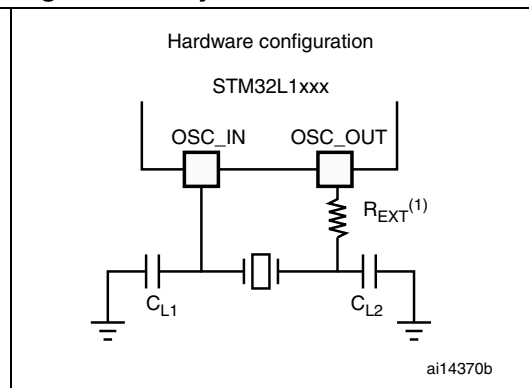


Figure 8. Crystal/ceramic resonators



1. The value of R_{EXT} depends on the crystal characteristics. A typical value is in the range of 5 to 6 R_S (resonator series resistance).
2. Load capacitance, C_L , has the following formula: $C_L = C_{L1} \times C_{L2} / (C_{L1} + C_{L2}) + C_{stray}$ where: C_{stray} is the pin capacitance and board or trace PCB-related capacitance. Typically, it is between 2 pF and 7 pF. Please refer to [Section 5: Recommendations on page 23](#) to minimize its value.

2.2.1 External source (HSE bypass)

In this mode, an external clock source must be provided. It can have a frequency of up to 32 MHz.

The external clock signal (square, sine or triangle) with a duty cycle of about 50%, has to drive the OSC_IN pin while the OSC_OUT pin must be left in the high impedance state (see [Figure 7](#) and [Figure 8](#)).

2.2.2 External crystal/ceramic resonator (HSE crystal)

The external oscillator frequency ranges from 1 to 24 MHz.

The external oscillator has the advantage of producing a very accurate rate on the main clock. The associated hardware configuration is shown in [Figure 8](#).

The resonator and the load capacitors have to be connected as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. The load capacitance values must be adjusted according to the selected oscillator.

For C_{L1} and C_{L2} it is recommended to use high-quality ceramic capacitors in the 5 pF to 25 pF range (typical), designed for high-frequency applications and selected to meet the requirements of the crystal or resonator. C_{L1} and C_{L2} , are usually the same value. The crystal manufacturer typically specifies a load capacitance that is the series combination of C_{L1} and C_{L2} . The PCB and MCU pin capacitances must be included when sizing C_{L1} and C_{L2} (10 pF can be used as a rough estimate of the combined pin and board capacitance).

Refer to the electrical characteristics sections in the datasheet of your product for more details.

2.3 LSE OSC clock

The low-speed external clock signal (LSE) can be generated from two possible clock sources:

- LSE user external clock (see [Figure 9](#))
- LSE external crystal/ceramic resonator (see [Figure 10](#))

Figure 9. External clock⁽¹⁾⁽²⁾

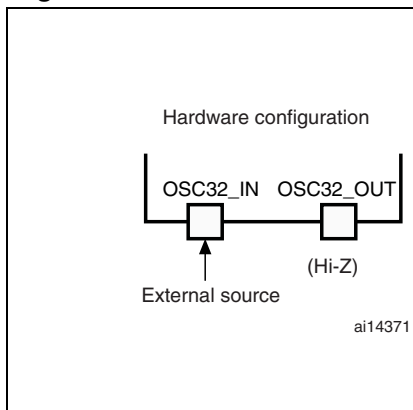
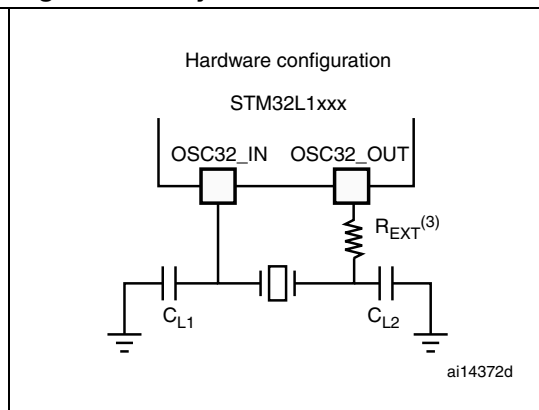


Figure 10. Crystal/ceramic resonators⁽²⁾



1. To avoid exceeding the maximum value of C_{L1} and C_{L2} (15 pF), it is strongly recommended to use a resonator with a load capacitance $C_L \leq 7$ pF. Never use a resonator with a load capacitance of 12.5 pF.
2. OSC32_IN and OSC_OUT pins can be also used as GPIOs, but it is recommended not to use them as both RTC and GPIO pins in the same application.
3. The value of R_{EXT} depends on the crystal characteristics. A 0Ω resistor works but, is not optimal. A typical value is in the range of 5 to 6 R_S (resonator series resistance). To fine tune the R_S value refer to AN2867 (Oscillator design guide for ST microcontrollers).

2.3.1 External source (LSE bypass)

In this mode, an external clock source must be provided. It must have a frequency of 32.768 kHz. The external clock signal (square, sine or triangle) with a duty cycle of about 50% has to drive the OSC32_IN pin while the OSC32_OUT pin must be left high impedance (see [Figure 9](#)).

2.3.2 External crystal/ceramic resonator (LSE crystal)

The LSE crystal is a 32.768 kHz low-speed external crystal or ceramic resonator. It has the advantage of providing a low-power, but highly accurate clock source to the real-time clock peripheral (RTC) for clock/calendar or other timing functions.

The oscillator can be switched on and off by software (default is off). When switched on, the oscillator is not stable immediately. A bit is set in the RCC_CSR register when the oscillator becomes stable and an interrupt can be generated if enabled in the RCC_CIR register.

The resonator and the load capacitors have to be connected as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. The load capacitance values must be adjusted according to the selected oscillator (see [Figure 10](#)).

2.4 Clock security system (CSS)

The clock security system can be activated by software. In this case, the clock detector is enabled after the HSE oscillator startup delay, and disabled when this oscillator is stopped. If a failure is detected on the HSE oscillator clock, this oscillator is automatically disabled and an interrupt is generated to inform the software about the failure (clock security system interrupt, CSSI), allowing the MCU to perform rescue operations. The CSSI is linked to the Cortex™-M3 NMI (non-maskable interrupt) exception vector.

If the HSE oscillator is used directly or indirectly as the system clock (indirectly means: it is used as the PLL input clock, and the PLL clock is used as the system clock), a detected failure causes the system clock to switch to the MSI oscillator and the external HSE oscillator to be disabled. If the HSE oscillator clock is the clock entry of the PLL used as the system clock when the failure occurs, the PLL is also disabled.

For details, see the STM32L15xxx reference manual (RM0038).

3 Boot configuration

3.1 Boot mode selection

In the STM32L1xxx, three different boot modes can be selected by means of the BOOT[1:0] pins as shown in [Table 2](#).

Table 2. Boot modes

BOOT mode selection pins		Boot mode	Aliasing
BOOT1	BOOT0		
x	0	Main Flash memory	Main Flash memory is selected as boot space
0	1	System memory	System memory is selected as boot space
1	1	Embedded SRAM	Embedded SRAM is selected as boot space

The values on the BOOT pins are latched on the 4th rising edge of SYSCLK after a reset. It is up to the user to set the BOOT1 and BOOT0 pins after reset to select the required boot mode.

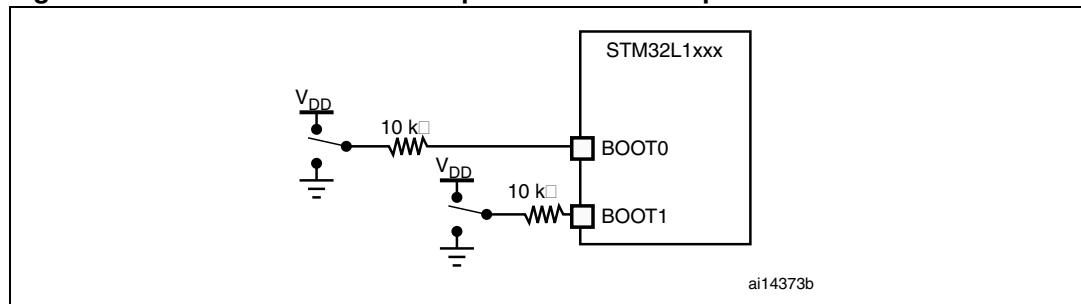
BOOT0 is a dedicated pin while BOOT1 is shared with a GPIO pin. Once BOOT1 has been sampled, the corresponding GPIO pin is free and can be used by the application.

The BOOT pins are also resampled when exiting Standby mode. Consequently, they must be kept in the required Boot mode configuration in Standby mode. After this startup delay has elapsed, the CPU fetches the top-of-stack value from address 0x0000 0000, and starts code execution from the boot memory starting from 0x0000 0004.

3.2 Boot pin connection

[Figure 11](#) shows the external connection required to select the boot memory of the STM32L1xxx.

Figure 11. Boot mode selection implementation example



1. Resistor values are given only as a typical example.

3.3 Embedded boot loader mode

The embedded boot loader is used to reprogram the Flash memory through one of the following interfaces: USART1 , USART2 or USB for medium+ and high density devices. This program is located in the system memory and is programmed by ST during production (see the STM32L Flash programming manual for further details).

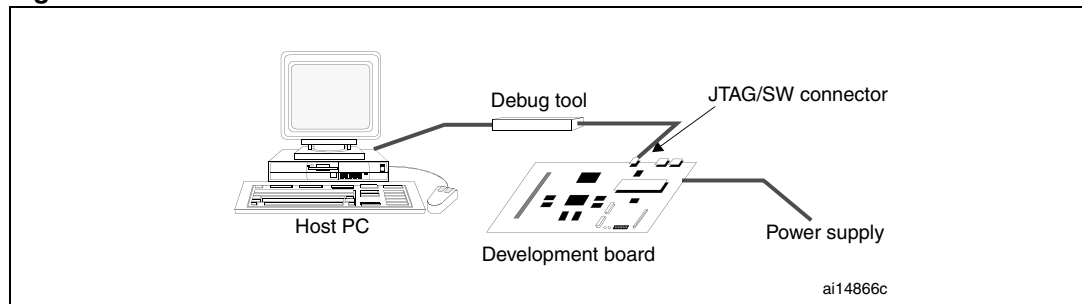
4 Debug management

4.1 Introduction

The host/target interface is the hardware equipment that connects the host to the application board. This interface is made of three components: a hardware debug tool, a JTAG or SW connector and a cable connecting the host to the debug tool.

Figure 12 shows the connection of the host to a development board. The evaluation board (STM32L152-EVAL and STM32L152D-EVAL) embeds the debug tools (ST-LINK) so it can be directly connected to the PC through an USB cable.

Figure 12. Host-to-board connection



4.2 SWJ debug port (serial wire and JTAG)

The STM32L1xxx core integrates the serial wire/JTAG debug port (SWJ-DP). It is an ARM® standard CoreSight™ debug port that combines a JTAG-DP (5-pin) interface and a SW-DP (2-pin) interface.

- The JTAG debug port (JTAG-DP) provides a 5-pin standard JTAG interface to the AHP-AP port
- The serial wire debug port (SW-DP) provides a 2-pin (clock + data) interface to the AHP-AP port

In the SWJ-DP, the two JTAG pins of the SW-DP are multiplexed with some of the five JTAG pins of the JTAG-DP.

4.3 Pinout and debug port pins

The STM32L1xxx MCU is offered in various packages with different numbers of available pins. As a result, some functionality related to the pin availability may differ from one package to another.

4.3.1 SWJ debug port pins

Five pins are used as outputs for the SWJ-DP as *alternate functions* of general-purpose I/Os (GPIOs). These pins, shown in [Table 3](#), are available on all packages.

Table 3. Debug port pin assignment

SWJ-DP pin name	JTAG debug port		SW debug port		Pin assignment
	Type	Description	Type	Debug assignment	
JTMS/SWDIO	I	JTAG test mode selection	I/O	Serial wire data input/output	PA13
JTCK/SWCLK	I	JTAG test clock	I	Serial wire clock	PA14
JTDI	I	JTAG test data input	-	-	PA15
JTDO/TRACESWO	O	JTAG test data output	-	TRACESWO if async trace is enabled	PB3
JNTRST	I	JTAG test nReset	-	-	PB4

4.3.2 Flexible SWJ-DP pin assignment

After reset (SYSRESETn or PORESETn), all five pins used for the SWJ-DP are assigned as dedicated pins which are immediately usable by the debugger host (note that the trace outputs are not assigned except if explicitly programmed by the debugger host).

However, the STM32L1xxx MCU implements a register to disable all or part of the SWJ-DP port, and so releases the associated pins for general-purpose I/O usage. This register is mapped on an APB bridge connected to the Cortex™-M3 system bus. It is programmed by the user software program and not by the debugger host.

[Table 4](#) shows the different possibilities for releasing some pins.

Table 4. SWJ I/O pin availability

Available debug ports	SWJ I/O pin assigned				
	PA13 / JTMS / SWDIO	PA14 / JTCK / SWCLK	PA15 / JTDI	PB3 / JTDO	PB4 / JNTRST
Full SWJ (JTAG-DP + SW-DP) - reset state	X	X	X	X	X
Full SWJ (JTAG-DP + SW-DP) but without JNTRST	X	X	X	X	
JTAG-DP disabled and SW-DP enabled	X	X			
JTAG-DP disabled and SW-DP disabled	Released				

For more details, see the STM32L15xx reference manual (RM0038).

4.3.3 Internal pull-up and pull-down resistors on JTAG pins

The JTAG input pins must *not* be floating since they are directly connected to flip-flops which control the debug mode features. Special care must be taken with the SWCLK/TCK pin that is directly connected to the clock of some of these flip-flops.

To avoid any uncontrolled I/O levels, the STM32L1xxx embeds internal pull-up and pull-down resistors on the JTAG input pins:

- JNTRST: internal pull-up
- JTDI: internal pull-up
- JTMS/SWDIO: internal pull-up
- TCK/SWCLK: internal pull-down

Once a JTAG I/O is released by the user software, the GPIO controller takes control again. The reset states of the GPIO control registers put the I/Os in the following equivalent states:

- JNTRST: input pull-up
- JTDI: input pull-up
- JTMS/SWDIO: input pull-up
- JTCK/SWCLK: input pull-down
- JTDO: input floating

The software can then use these I/Os as standard GPIOs.

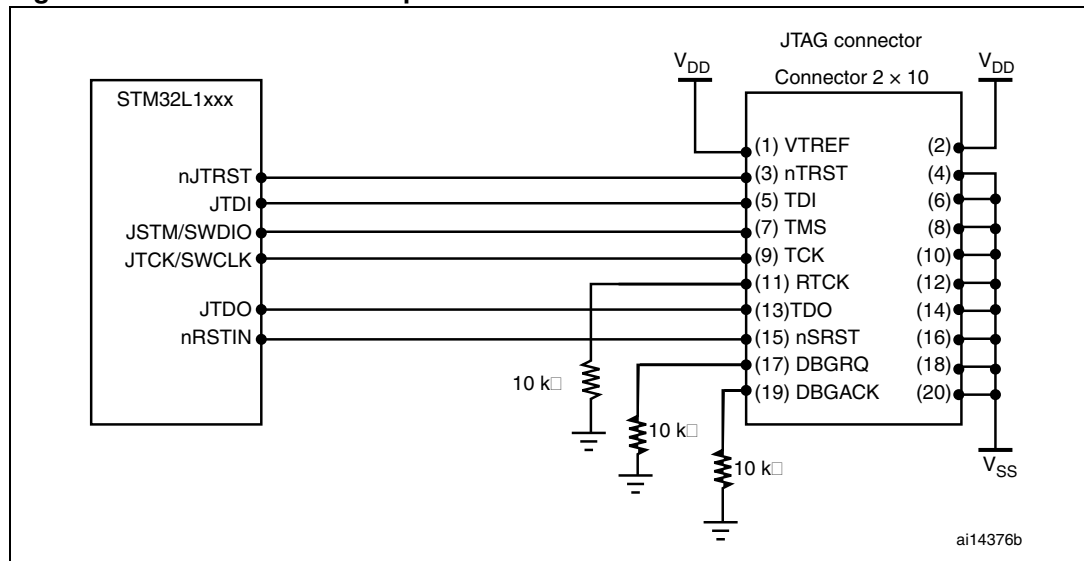
Note: The JTAG IEEE standard recommends to add pull-up resistors on TDI, TMS and nTRST but, there is no special recommendation for TCK. However, for the STM32L1xxx, an integrated pull-down resistor is used for JTCK.

Having embedded pull-up and pull-down resistors removes the need to add external resistors.

4.3.4 SWJ debug port connection with standard JTAG connector

Figure 13 shows the connection between the STM32L1xxx and a standard JTAG connector.

Figure 13. JTAG connector implementation



5 Recommendations

5.1 Printed circuit board

For technical reasons, it is best to use a multilayer printed circuit board (PCB) with a separate layer dedicated to ground (V_{SS}) and another dedicated to the V_{DD} supply. This provides good decoupling and a good shielding effect. For many applications, economical reasons prohibit the use of this type of board. In this case, the major requirement is to ensure a good structure for ground and for the power supply.

5.2 Component position

A preliminary layout of the PCB must separate the different circuits according to their EMI contribution in order to reduce cross-coupling on the PCB, that is noisy, high-current circuits, low-voltage circuits, and digital components.

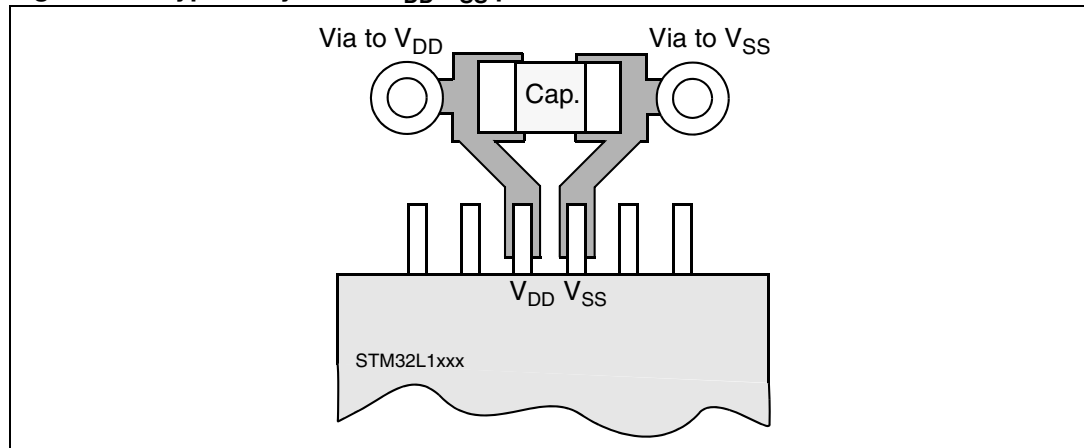
5.3 Ground and power supply (V_{SS} , V_{DD})

Every block (noisy, low-level sensitive, digital, etc.) should be grounded individually and all ground returns should be to a single point. Loops must be avoided or have a minimum area. The power supply should be implemented close to the ground line to minimize the area of the supply loop. This is due to the fact that the supply loop acts as an antenna, and is therefore the main transmitter and receiver of EMI. All component-free PCB areas must be filled with additional grounding to create a kind of shielding (especially when using single-layer PCBs).

5.4 Decoupling

All pins need to be properly connected to the power supplies. These connections, including pads, tracks and vias should have as low an impedance as possible. This is typically achieved with thick track widths and, preferably, the use of dedicated power supply planes in multilayer PCBs.

In addition, each power supply pair should be decoupled with filtering ceramic capacitors C (100 nF) and a Tantalum or Ceramic capacitor C of about 10 μ F connected in parallel on the STM32L1xxx device. These capacitors need to be placed as close as possible to, or below, the appropriate pins on the underside of the PCB. Typical values are 10 nF to 100 nF, but exact values depend on the application needs. [Figure 14](#) shows the typical layout of such a V_{DD}/V_{SS} pair.

Figure 14. Typical layout for V_{DD}/V_{SS} pair

5.5 Other signals

When designing an application, the EMC performance can be improved by closely studying the following:

- Signals for which a temporary disturbance affects the running process permanently (which is the case for interrupts and handshaking strobe signals but, not the case for LED commands).
For these signals, a surrounding ground trace, shorter lengths, and the absence of noisy and sensitive traces nearby (crosstalk effect) improve EMC performance.
For digital signals, the best possible electrical margin must be reached for the two logical states and slow Schmitt triggers are recommended to eliminate parasitic states.
- Noisy signals (example, clock)
- Sensitive signals (example, high impedance)

5.6 Unused I/Os and features

All microcontrollers are designed for a variety of applications and often a particular application does not use 100% of the MCU resources.

To increase EMC performance, unused clocks, counters or I/Os, should not be left free, example, I/Os should be set to "0" or "1" (pull-down or pull-up respectively to the unused I/O pins) and unused features should be "frozen" or disabled.

6 Reference design

6.1 Description

The reference design shown in [Figure 15](#), is based on the STM32L152VB(T6).

This reference design can be tailored to any STM32L1xxx device with a different package, using the pin correspondence given in [Table 7: Reference connection for all packages](#).

6.1.1 Clock

Two clock sources are used for the microcontroller:

- LSE: X1– 32.768 kHz crystal for the embedded RTC
- HSE: X2– 8 MHz crystal for the STM32L1xxx microcontroller

Refer to [Section 2: Clocks on page 14](#).

6.1.2 Reset

The reset signal in [Figure 15](#) is active low. The reset sources include:

- Reset button (B1)
- Debugging tools via the connector CN1

Refer to [Section 1.3: Reset and power supply supervisor on page 9](#).

6.1.3 Boot mode

The boot option is configured by setting switches SW2 (Boot 0) and SW1 (Boot 1). Refer to [Section 3: Boot configuration on page 18](#).

Note: In low-power mode (more specially in Standby mode) the boot mode is mandatory to be able to connect to tools (the device should boot from the SRAM).

6.1.4 SWJ interface

The reference design shows the connection between the STM32L1xxx and a standard JTAG connector. Refer to [Section 4: Debug management on page 20](#).

Note: It is recommended to connect the reset pins so as to be able to reset the application from the tools.

6.1.5 Power supply

Refer to [Section 1: Power supplies on page 6](#).

6.2 Component references

Table 5. Mandatory components

Id	Components name	Reference	Quantity	Comments
1	Microcontroller	STM32L152VB(T6)	1	100-pin package
2	Capacitors	100 nF	3 ... 6	Ceramic capacitors (decoupling capacitors)
3	Capacitor	10 μ F	1	Ceramic capacitor (decoupling capacitor)
4	Capacitor	1 μ F	2	Ceramic capacitor (LCD booster or decoupling capacitor)

Table 6. Optional components

Id	Components name	Reference	Quantity	Comments
R2, R4, R5, R7, R8	Resistor	10 k Ω	9	Pull-up and pull-down for JTAG and Boot mode.
R6	Resistor	0 Ω	1	Used for HSE: the value depends on the crystal characteristics. A typical value is 390 Ω .
R1	Resistor	0 Ω	2	Used for LSE: the value depends on the crystal characteristics. This resistor value is given only as a typical example.
R3	Resistor	0 Ω	1	For low pass filter
C3, C5, C10, C11, C12, C13, C14, C15	Capacitor	100 nF	8	Ceramic capacitor
C1, C2	Capacitor	6.8 pF	2	Used for LSE: the value depends on the crystal characteristics. Fits for MC-306 32.768K-E3, which has a load capacitance of 6 pF.
C7, C8	Capacitor	20 pF	2	Used for HSE: the value depends on the crystal characteristics.
C4, C6	Capacitor	1 μ F	2	Ceramic capacitors (decoupling capacitors)
C9	Capacitor	10 μ F	1	Ceramic capacitors (decoupling capacitors)
X2	Quartz	8 MHz	1	Used for HSE
X1	Quartz	32 kHz	1	Used for LSE
CN1	JTAG connector	HE10	1	
SW1, SW2	Switch	3V3	2	Used to select the right boot mode
B1	Push-button	B1	1	

Figure 15. STM32L152VB(T6) microcontroller reference schematic

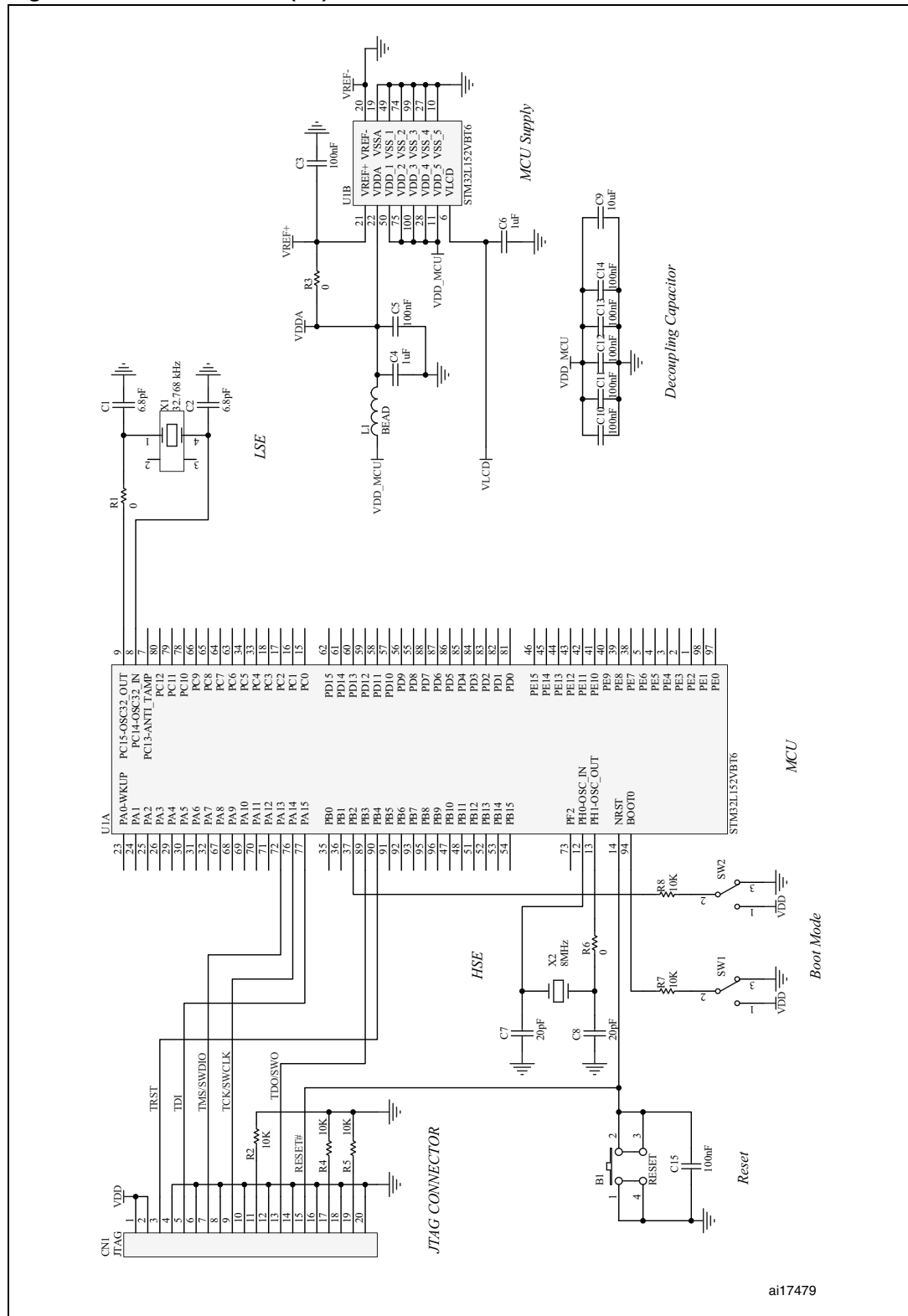


Table 7. Reference connection for all packages

Pin name	Pin numbers for LQFP packages				Pin numbers for BGA packages			Pin numbers for UFQFPN package
	144 pins	100 pins	64 pins	48 pins	132 pins	100 pins	64 pins	48 pins
PH0-OSC_IN	23	12	5	5	F1	F1	C1	5
PH1-OSC_OUT	24	13	6	6	G1	G1	D1	6
PC15-OSC32_OUT	9	9	4	4	E1	E1	B1	4
PC14-OSC32_IN	8	8	3	3	D1	D1	A1	3
BOOT0	138	94	60	44	A4	A4	B4	44
PB2-BOOT1	48	37	28	20	L6	L6	G6	20
NRST	25	14	7	7	H2	H2	E1	7
PA13	105	72	46	34	A11	A11	A8	34
PA14	109	76	49	37	A10	A10	A7	37
PA15	110	77	50	38	A9	A9	A6	38
PB4	134	90	56	40	A7	A7	A4	40
PB3	133	89	55	39	A8	A8	A5	39
V _{SS_1}	71	49	31	23	F12	F12	D6	23
V _{SS_2}	107	74	47	35	F11	F11	D5	35
V _{SS_3}	143	99	63	47	D3	D3	D4	47
V _{SS_4}	38	27	18	-	-	E3	C2	—
V _{SS_5}	16	10	-	-	F2	F2	-	—
V _{SS_6}	51	-	-	-	E3	-	-	—
V _{SS_7}	61	-	-	-	-	-	-	—
V _{SS_8}	83	-	-	-	-	-	-	—
V _{SS_9}	94	-	-	-	F6	-	-	—
V _{SS_10}	120	-	-	-	F7	-	-	—
V _{SS_11}	130	-	-	-	-	-	-	—
V _{DD_1}	72	50	32	24	G12	G12	E6	24
V _{DD_2}	108	75	48	36	G11	G11	E5	36
V _{DD_3}	144	100	64	48	C4	C4	E4	48
V _{DD_4}	39	28	19	-	-	H3	D2	—
V _{DD_5}	17	11	-	-	G2	G2	-	—
V _{DD_6}	52	-	-	-	H3	-	-	—
V _{DD_7}	62	-	-	-	-	-	-	—
V _{DD_8}	84	-	-	-	-	-	-	—

Table 7. Reference connection for all packages

Pin name	Pin numbers for LQFP packages				Pin numbers for BGA packages			Pin numbers for UFQFPN package
	144 pins	100 pins	64 pins	48 pins	132 pins	100 pins	64 pins	48 pins
V _{DD_9}	95	--	-	-	G6	-	-	—
V _{DD_10}	121	--	-	-	G7	-	-	—
V _{DD_11}	131	-	-	-	-	-	-	—
V _{REF+}	32	21	-	-	L1	L1	G1	—
V _{REF-}	31	20	-	-	-	K1	-	—
V _{SSA}	30	19	12	8	J1	J1	F1	8
V _{DDA}	33	22	13	9	M1	M1	H1	9
V _{LCD}	6	6	1	1	E2	E2	B2	1

7 Revision history

Table 8. Document revision history

Date	Revision	Changes
28-Jun-2010	1	Initial release
29-Jul-2010	2	Updated the following sections: Section 1.1: Introduction , Section 1.1.1: Independent A/D converter supply and reference voltage , Section 1.1.2: Independent LCD supply , Section 1.3.1: Power-on reset (POR)/power-down reset (PDR), brownout reset (BOR) , and Section 1.3.4: System reset . Added Section 1.3.3: Brownout reset (BOR) . Replaced Figure 3 , Figure 4 , Figure 5 , and Figure 6 . In Section 2.3.2 , replaced RCC_ICR register by RCC_CIR register. Replaced PF0_OSC_IN and PF1_OSC_OUT by PH0_OSC_IN and PH1_OSC_OUT in Figure 15 and Table 7 . Updated value of C4 and C9 decoupling capacitors in Figure 15 .
01-Oct-2010	3	Modified Section 1.3.4: System reset on page 13 Updated capacitors in Table 5 and Table 5
07-Apr-2011	4	Changed title of document from "STM32L1xxx hardware development: getting started" to "Getting started with STM32L1xxx hardware development". Modified Section 2.1: MSI clock , Section 1.2: Power supply schemes , and Figure 2 .
29-Jun-2011	5	Updated Section 1.1.1: Independent A/D converter supply and reference voltage and Section 1.2: Power supply schemes .
30-May-2012	6	Updated to adapt to STM32L1xxx High density devices

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